

HiPerFET™ Power MOSFETs

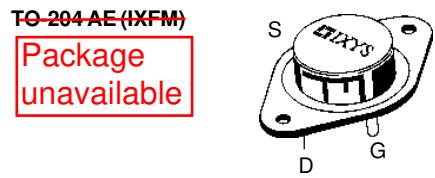
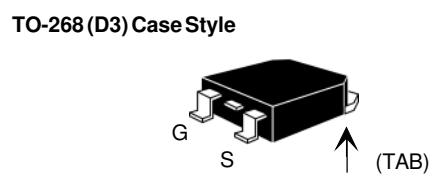
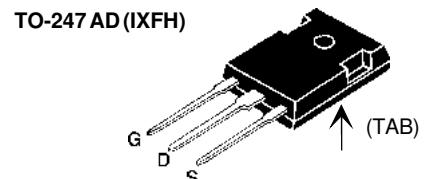
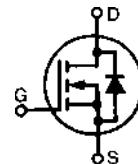
N-Channel Enhancement Mode
High dv/dt, Low t_{rr} , HDMOS™ Family

Obsolete:
IXFM42N20
IXFM50N20

IXFH/IXFM42N20
IXFH/IXFM/IXFT50N20
IXFH/IXFT58N20

V_{DSS}	I_{D25}	R_{DS(on)}
200 V	42 A	60 mΩ
200 V	50 A	45 mΩ
200 V	58 A	40 mΩ

$t_{rr} \leq 200 \text{ ns}$



G = Gate,
S = Source,

D = Drain,
TAB = Drain

Symbol	Test Conditions	Maximum Ratings		
V_{DSS}	$T_c = 25^\circ\text{C}$ to 150°C	200	V	
V_{DGR}	$T_c = 25^\circ\text{C}$ to 150°C ; $R_{GS} = 1 \text{ M}\Omega$	200	V	
V_{GS}	Continuous	± 20	V	
V_{GSM}	Transient	± 30	V	
I_{D25}	$T_c = 25^\circ\text{C}$	42N20 50N20 58N20	42 50 58	A
I_{DM}	$T_c = 25^\circ\text{C}$, pulse width limited by T_{JM}	42N20 50N20 58N20	168 200 232	A
I_{AR}	$T_c = 25^\circ\text{C}$	42N20 50N20 58N20	42 50 58	A
E_{AR}	$T_c = 25^\circ\text{C}$	30	mJ	
dv/dt	$I_s \leq I_{DM}$, $di/dt \leq 100 \text{ A}/\mu\text{s}$, $V_{DD} \leq V_{DSS}$, $T_j \leq 150^\circ\text{C}$, $R_G = 2 \Omega$	5	V/ns	
P_D	$T_c = 25^\circ\text{C}$	300	W	
T_J		-55 ... +150	°C	
T_{JM}		150	°C	
T_{stg}		-55 ... +150	°C	
T_L	1.6 mm (0.062 in.) from case for 10 s	300	°C	
M_d	Mounting torque	1.13/10	Nm/lb.in.	
Weight		TO-204 = 18 g, TO-247 = 6 g		

Symbol	Test Conditions	Characteristic Values		
		($T_j = 25^\circ\text{C}$, unless otherwise specified)	min.	typ.
V_{DSS}	$V_{GS} = 0 \text{ V}$, $I_D = 250 \mu\text{A}$	200		V
V_{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 4 \text{ mA}$	2	4	V
I_{GSS}	$V_{GS} = \pm 20 \text{ V}_{DC}$, $V_{DS} = 0$		± 100	nA
I_{DSS}	$V_{DS} = 0.8 \cdot V_{DSS}$ $V_{GS} = 0 \text{ V}$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	200 1	μA mA

IXYS reserves the right to change limits, test conditions, and dimensions.

91522H (2/98)

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Features

- International standard packages
- Low $R_{DS(on)}$ HDMOS™ process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
 - easy to drive and to protect
- Fast intrinsic Rectifier

Applications

- DC-DC converters
- Synchronous rectification
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- AC motor control
- Temperature and lighting controls
- Low voltage relays

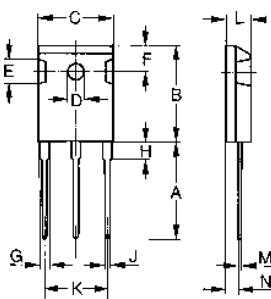
Advantages

- Easy to mount with 1 screw (TO-247) (isolated mounting screw hole)
- High power surface mountable package
- High power density

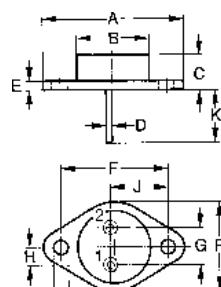
Symbol	Test Conditions	Characteristic Values		
	($T_J = 25^\circ\text{C}$, unless otherwise specified)	Min.	Typ.	Max.
$R_{DS(on)}$	$V_{GS} = 10 \text{ V}, I_D = 0.5 I_{D25}$	42N20		0.060 Ω
		50N20		0.045 Ω
		58N20		0.040 Ω
	Pulse test, $t \leq 300 \mu\text{s}$, duty cycle $d \leq 2\%$			
g_{fs}	$V_{DS} = 10 \text{ V}; I_D = 0.5 I_{D25}$, pulse test	20	32	S
C_{iss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	4400		pF
C_{oss}		800		pF
C_{rss}		285		pF
$t_{d(on)}$	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}$	18	25	ns
t_r		15	20	ns
$t_{d(off)}$		72	90	ns
t_i		16	25	ns
$Q_{g(on)}$	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}$	190	220	nC
Q_{gs}		35	50	nC
Q_{gd}		95	110	nC
R_{thJC}	(TO-247 and TO-204 Case styles)		0.42	K/W
R_{thCK}		0.25		K/W

Symbol	Test Conditions	Characteristic Values		
		($T_J = 25^\circ\text{C}$, unless otherwise specified)	Min.	Typ.
I_s	$V_{GS} = 0 \text{ V}$	42N20		A
		50N20		A
		58N20		A
I_{SM}	Repetitive; pulse width limited by T_{JM}	42N20		A
		50N20		A
		58N20		A
V_{SD}	$I_F = I_s, V_{GS} = 0 \text{ V},$ Pulse test, $t \leq 300 \mu\text{s}$, duty cycle $d \leq 2\%$		1.5	V
t_{rr}	$I_F = 25 \text{ A},$ $-di/dt = 100 \text{ A}/\mu\text{s},$ $V_R = 100 \text{ V}$	$T_J = 25^\circ\text{C}$	200	ns
		$T_J = 125^\circ\text{C}$	300	ns
Q_{RM}		$T_J = 25^\circ\text{C}$	1.5	μC
		$T_J = 125^\circ\text{C}$	2.6	μC
I_{RM}		$T_J = 25^\circ\text{C}$	19	A
		$T_J = 125^\circ\text{C}$	23	A

TO-268AA (D ³ PAK)	Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
	A	4.9	5.1	.193	.201
	A ₁	2.7	2.9	.106	.114
	A ₂	.02	.25	.001	.010
	b	1.15	1.45	.045	.057
	b ₂	1.9	2.1	.75	.83
	C	.4	.65	.016	.026
	D	13.80	14.00	.543	.551
	E	15.85	16.05	.624	.632
	E ₁	13.3	13.6	.524	.535
	e	5.45	BSC	.215	BSC
	H	18.70	19.10	.736	.752
	L	2.40	2.70	.094	.106
	L1	1.20	1.40	.047	.055
	L2	1.00	1.15	.039	.045
	L3	0.25	BSC	.010	BSC
	L4	3.80	4.10	.150	.161

TO-247 AD (IXFH) Outline


Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102

TO-204 AE (IXFM) Outline


Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	38.61	39.12	1.520	1.540
B	-	22.22	-	0.875
C	6.40	11.40	0.252	0.449
D	1.45	1.60	0.057	0.063
E	1.52	3.43	0.060	0.135
F	30.15	BSC	1.187	BSC
G	10.67	11.17	0.420	0.440
H	5.21	5.71	0.205	0.225
J	16.64	17.14	0.655	0.675
K	11.18	12.19	0.440	0.480
Q	3.84	4.19	0.151	0.165
R	25.16	26.66	0.991	1.050

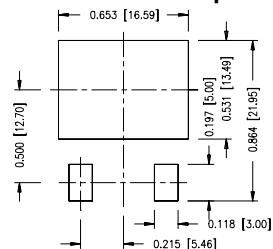
Min. Recommended Footprint


Fig. 1 Output Characteristics

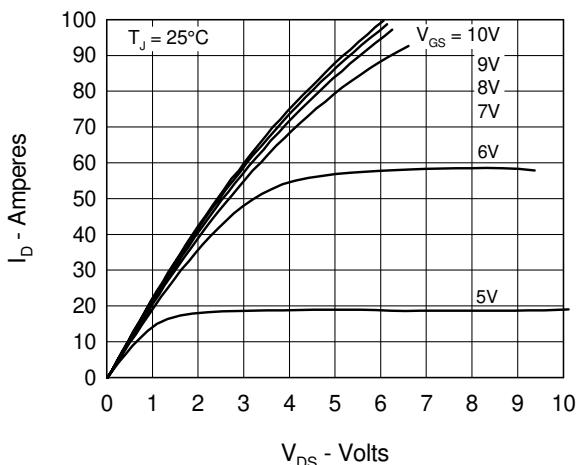


Fig. 3 $R_{DS(on)}$ vs. Drain Current

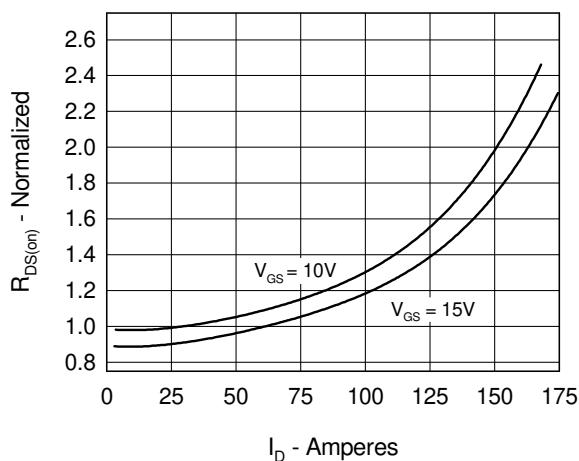


Fig. 5 Drain Current vs. Case Temperature

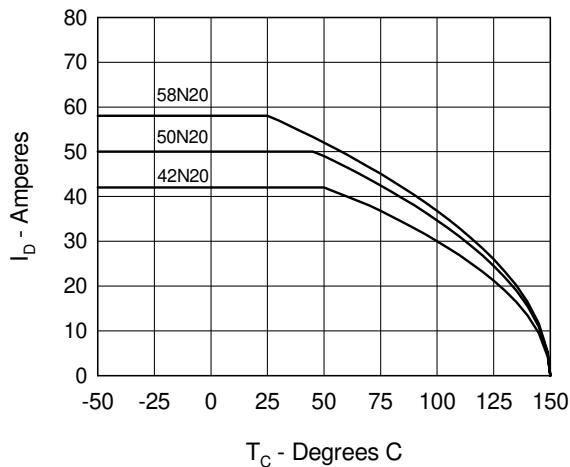


Fig. 2 Input Admittance

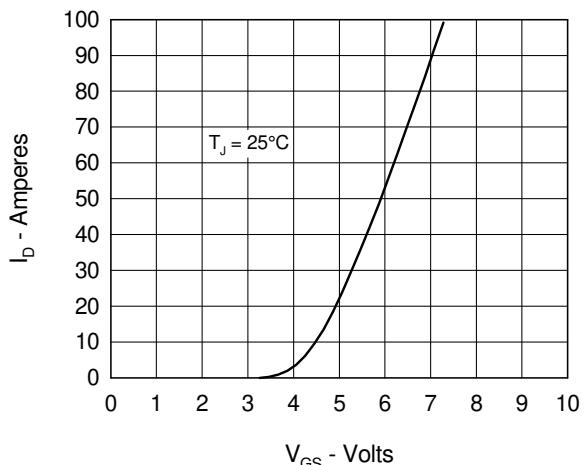


Fig. 4 Temperature Dependence of Drain to Source Resistance

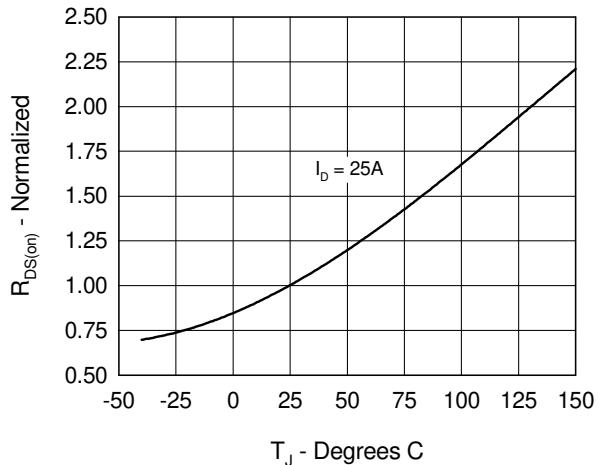


Fig. 6 Temperature Dependence of Breakdown and Threshold Voltage

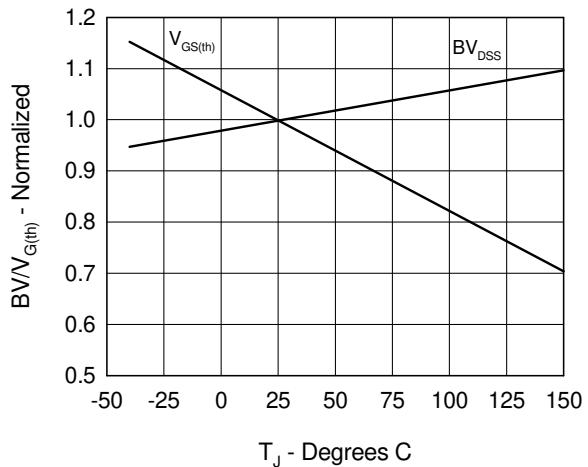


Fig.7 Gate Charge Characteristic Curve

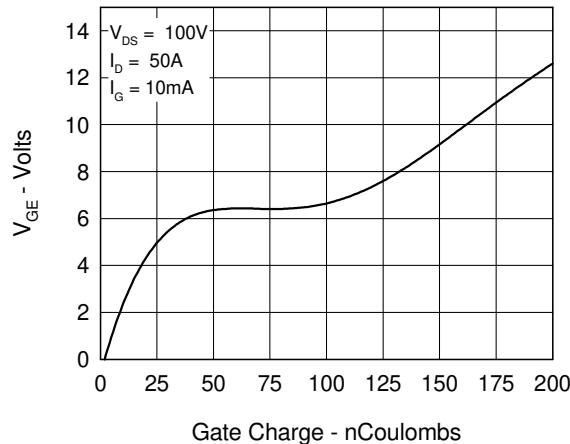


Fig.8 Forward Bias Safe Operating Area

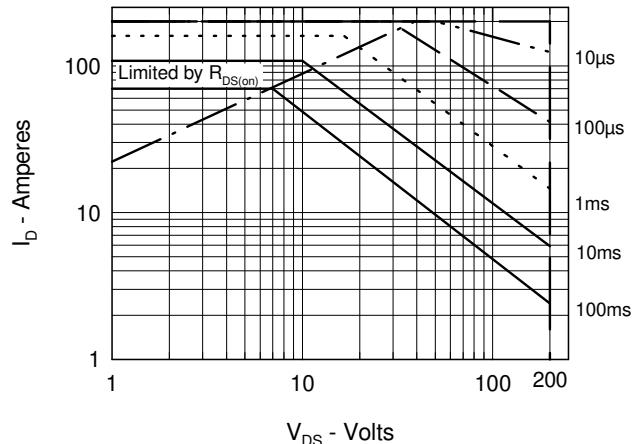


Fig.9 Capacitance Curves

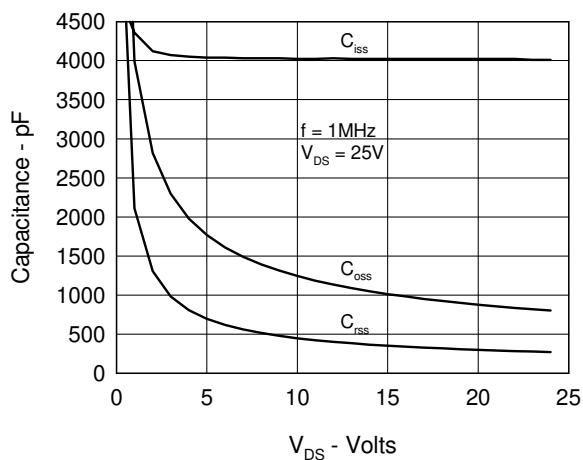


Fig.10 Source Current vs. Source to Drain Voltage

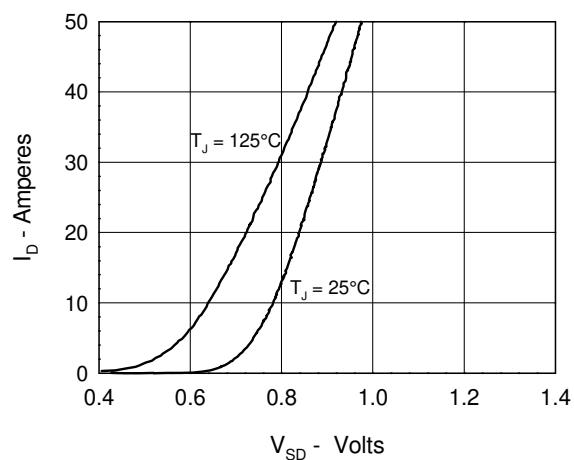
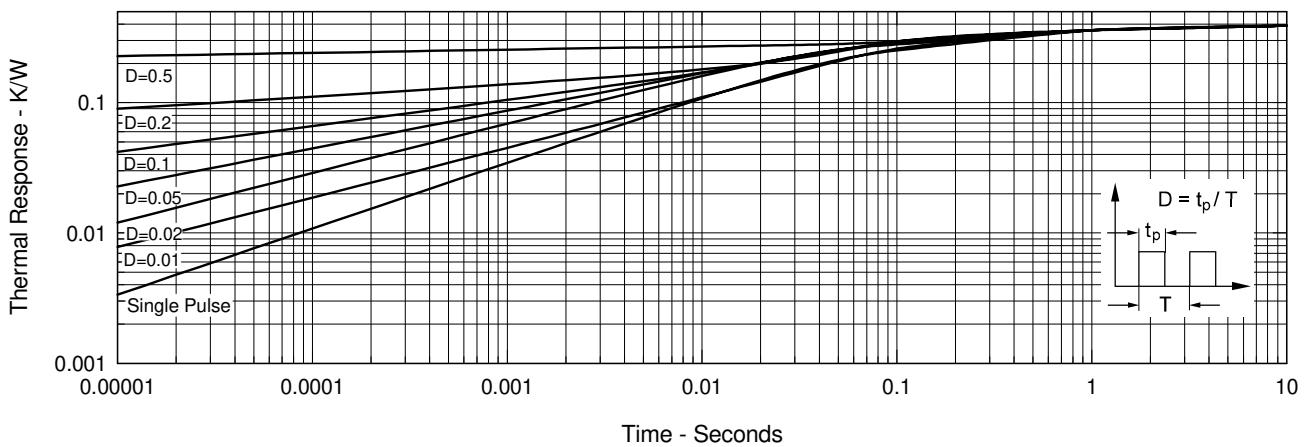


Fig.11 Transient Thermal Impedance





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